



#### **45V PNP SMALL SIGNAL TRANSISTOR IN SOT323**

#### **Features**

- Ideally Suited for Automatic Insertion
- Epitaxial Planar Die Construction
- Complementary NPN Types Available (BC817-xxW)
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

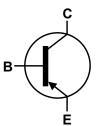
### **Mechanical Data**

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight 0.006 grams (approximate)

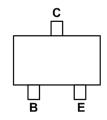








Device Symbol



Top View Pin-Out

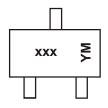
### Ordering Information (Notes 4)

Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BC807-16W-7	K5A	7	8	3,000
BC807-25W-7	K5B	7	8	3,000
BC807-40W-7	K5C	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



 $\begin{array}{l} xxx = \mbox{Product Type Marking Code} \\ (\mbox{Please see Ordering Information}) \\ \mbox{YM} = \mbox{Date Code Marking} \\ \mbox{Y or } \overline{\mbox{Y}} = \mbox{Year (ex: A = 2013)} \\ \mbox{M or } \overline{\mbox{M}} = \mbox{Month (ex: 9 = September)} \\ \end{array}$ 

Date Code Key

Year	2010	20	011	2012	2	2013	2014		2015	2016		2017
Code	Χ		Υ	Z		Α	В		С	D		Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-45	V
Emitter-Base Voltage	V <sub>EBO</sub>	-6	V
Continuous Collector Current	Ic	-500	mA
Peak Collector Current	I <sub>CM</sub>	-1.0	Α
Peak Base Current	I <sub>BM</sub>	-200	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	$P_D$	200	mW
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	625	°C/W
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-65 to +150	°C	

## ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Charact	eristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage (Note 7)		$BV_CEO$	-45	_	_	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage		BV <sub>EBO</sub>	-6	_	_	V	I <sub>C</sub> = -100μA
Collector-Emitter Cutoff Current		I <sub>CES</sub>	_	_	-100 -5.0	nΑ μΑ	V <sub>CE</sub> = -45V V <sub>CE</sub> = -25V, T <sub>J</sub> = +150°C
Collector		I <sub>CBO</sub>	_	_	-100 -5.0	nA μA	$V_{CB} = -20V$ $V_{CB} = -20V$ , $T_{J} = +150$ °C
Emitter-Base Cutoff Current	Emitter-Base Cutoff Current		_	_	-100	nA	V <sub>EB</sub> = -5V
	BC807-16W-7 BC807-25W-7 BC807-40W-7	_	100 160 250		250 400 600		I <sub>C</sub> = -100mA, V <sub>CE</sub> = -1.0V
DC Current Gain (Note 7)	BC807-16W-7 BC807-25W-7 BC807-40W-7	- h <sub>FE</sub>	60 100 170	_	_	_	I <sub>C</sub> = -300mA, V <sub>CE</sub> = -1.0V
Collector-Emitter Saturation Voltage (Note 7)		$V_{CE(sat)}$	_	_	-700	mV	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Base-Emitter Voltage (Note 7)		$V_{BE}$	_	_	-1200	mV	$I_C = -300 \text{mA}, V_{CE} = -1.0 \text{V}$
Gain Bandwidth Product		f⊤	100	_	_	MHz	$V_{CE} = -5.0V$ , $I_{C} = -10mA$ , $f = 50MHz$
Collector-Base Capacitance		$C_{CBO}$	_	_	12	pF	$V_{CB} = -10V$ , $f = 1.0MHz$

Notes:

<sup>5.</sup> For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

<sup>7.</sup> Measured under pulsed conditions. Pulse width  $\leqslant$  300µs. Duty cycle  $\leqslant$  2%.



### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

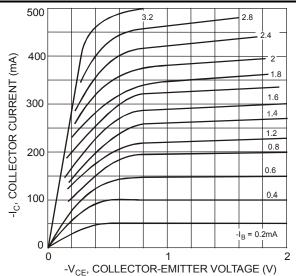


Figure 1 Typical Collector Current vs. Collector-Emitter Voltage

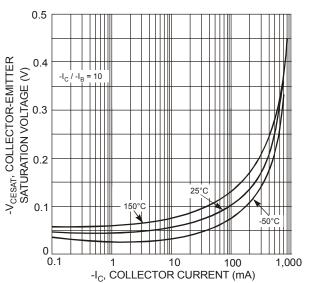


Figure 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

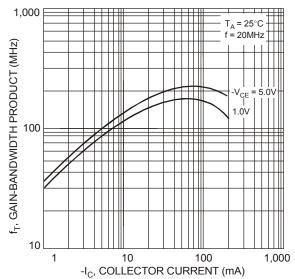


Figure 5 Typical Gain-Bandwidth Product vs. Collector Current

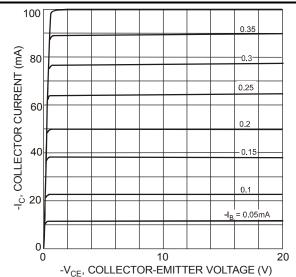


Figure 2 Typical Collector Current vs. Collector-Emitter Voltage

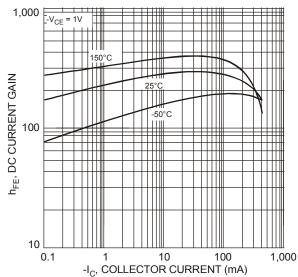
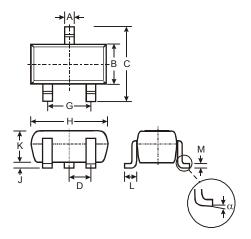


Figure 4 Typical DC Current Gain vs. Collector Current



## **Package Outline Dimensions**

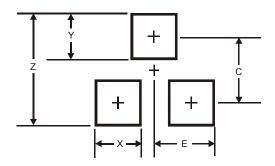
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT323						
Dim	Min	Max	Тур				
Α	0.25	0.40	0.30				
В	1.15	1.35	1.30				
С	2.00	2.20	2.10				
D	-	-	0.65				
G	1.20	1.40	1.30				
Н	1.80	2.20	2.15				
J	0.0	0.10	0.05				
K	0.90	1.00	1.00				
L	0.25	0.40	0.30				
M	0.10	0.18	0.11				
α	0°	8°	-				
All	All Dimensions in mm						

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
X	0.7
Υ	0.9
С	1.9
E	1.0



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